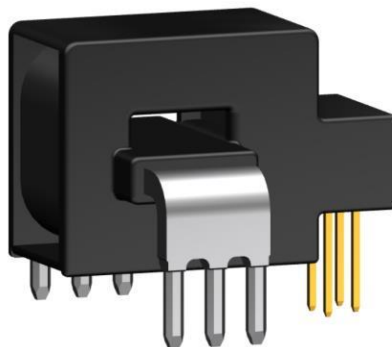


Current Sensor

Product Series: STK-PL/Z

Part number: STK-50PL/Z
STK-50PL/Z1
STK-50PL/Z3
STK-80PL/Z
STK-100PL/Z
STK-100PL/Z2
STK-120PL/Z
STK-150PL/Z
STK-180PL/Z

Version: Ver1.3



Sinomags Technology Co., Ltd

Web site: www.sinomags.com

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1. Summary

The STK-PL/Z series is based on open-loop technology and design. It is suitable for DC, AC, pulse and any type of irregular current measurement under isolated conditions. The nominal current range of STK-PL/Z current sensors includes 50A,80A,100A,120A,150A,180A.

Typical applications

- PV combiner box
- PV inverter (MPPT & AC)
- motor driver controller
- SMPS & UPS
- Battery management system

Standards

- EN50178:1997
- IEC 61010-1:2010
- IEC 61326-1:2012

General parameter

Parameter	Symbol	Unit	Value
Working temperature	T _A	°C	-40 ~ 105
Storage temperature	T _{stg}	°C	-40 ~ 105
Mass	m	g	10

Absolute maximum rating

Parameter	Symbol	Unit	Value
Supply voltage (non-destructive)	V _C	V	6.0
ESD rating (HBM)	U _{ESD}	kV	4
ESD rating (CDM)	U _{CDM}	kV	1.5

Remark: the unrecoverable damage may occur when the product works on the conditions over the absolute maximum ratings. Long-time working on the absolute maximum ratings may cause the degradation on performance and reliability.

Ratings

Parameter	Symbol	Unit	Value
Primary involved potential		V AC/DC	600
Ambient operating temperature	T_A	°C	105
Primary current	I_p	A	According to series primary current
Secondary supply voltage	U_c	V DC	5
Output voltage	V_out	V	0.1 ~ 4.9

Isolation parameter

Parameter	Symbol	Unit	Value	Comment
RMS voltage for AC test 50Hz/1 min	U _d	kV	5	
Impulse withstand voltage 1.2/50μs	Ū _w	kV	8	
Clearance distance (pri. -sec)	d _{Cl}	mm	8	Shortest distance through air
Creepage distance (pri. -sec)	d _{Cp}	mm	8	Shortest path along device body
Case material			V0 according to UL 94	
Application example		V	600	Reinforced insulation, CAT III, PD 2, non uniform field according EN 50178, IEC 61010
Application example		V	1000	Basic insulation, CAT III, PD 2, non uniform field according EN 50178, IEC 61010
Application example		V	1500	Basic insulation, CAT III, PD 2, according to IEC 62109-1 Altitude ≤ 3000 m
Application example		V	600	CAT III, PD 2, according to UL 508

2. STK-50PL/Z Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 5\text{V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		50		
Primary current measuring range	I_{pm}	A	-125		125	
Supply voltage	V_{cc}	V	4.75	5	5.25	
Current consumption	I_{cc}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		16		$800\text{mV} @ I_{pn}$
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Rated linearity error	$Non-L_{pn}$	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	$Non-L_{pm}$	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.4		@ 10% of I_{pn}
Step response time	t_{res}	μs		1.5		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V_{noise}	mVpp				
DC ~ 10 kHz			10			
DC ~ 100 kHz	15					
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^\circ\text{C} \sim 105^\circ\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^\circ\text{C} \sim 105^\circ\text{C}$

3. STK-50PL/Z1 Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{CC} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		50		
Primary current measuring range	I_{pm}	A	-150		150	
Supply voltage	V_{CC}	V	4.75	5	5.25	
Current consumption	I_{CC}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.625		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		12.5		625 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Rated linearity error	Non- I_{pn}	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	Non- I_{pm}	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.4		@ 10% of I_{pn}
Step response time	t_{res}	μs		1.5		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^\circ\text{C} \sim 105^\circ\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^\circ\text{C} \sim 105^\circ\text{C}$

4. STK-50PL/Z3 Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 3.3\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		50		
Primary current measuring range	I_{pm}	A	-150		150	
Supply voltage	V_{cc}	V	3.135	3.3	3.465	
Current consumption	I_{cc}	mA		5	10	
Reference voltage	V_{ref}	V	1.63	1.65	1.67	Output function
Rated output voltage`	V_{FS}	V		0.46		$V_{out} - V_{ref} @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		$V_{out} @ 0\text{ A}$
Quiescent voltage	V_{off}	V	1.63	1.65	1.67	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of Voe	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		9.2		460 mV @ I_{pn}
Error of gain	Err_G	% G_{th}	-0.5		0.5	Trimmed in the factory @ 25°C
Temperature drift of gain	Err_G_TRange	% V_{FS}	-1.0		1.0	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Rated linearity error	Non-L	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	Non-L	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.4		@ 10% of I_{pn}
Step response time	t_{res}	μs		1.5		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^\circ\text{C} \sim 105^\circ\text{C}$	X_TRange	% of I_{pn}	-3		3	$-40^\circ\text{C} \sim 105^\circ\text{C}$

5. STK-80PL/Z Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 5\text{V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		80		
Primary current measuring range	I_{pm}	A	-200		200	
Supply voltage	V_{cc}	V	4.75	5	5.25	
Current consumption	I_{cc}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		10		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Rated linearity error	$Non-L_{pn}$	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	$Non-L_{pm}$	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.4		@ 10% of I_{pn}
Step response time	t_{res}	μs		1.5		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^\circ\text{C} \sim 105^\circ\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^\circ\text{C} \sim 105^\circ\text{C}$

6. STK-100PL/Z Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		100		
Primary current measuring range	I_{pm}	A	-250		250	
Supply voltage	V_{cc}	V	4.75	5	5.25	
Current consumption	I_{cc}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		8		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Rated linearity error	$Non-L_{pn}$	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	$Non-L_{pm}$	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.4		@ 10% of I_{pn}
Step response time	t_{res}	μs		1.5		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^\circ\text{C} \sim 105^\circ\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^\circ\text{C} \sim 105^\circ\text{C}$

7. STK-100PL/Z2 Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I _{pn}	A		100		
Primary current measuring range	I _{pm}	A	-200		200	
Supply voltage	V _{cc}	V	4.75	5	5.25	
Current consumption	I _{cc}	mA		5	10	
Reference voltage	V _{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V _{FS}	V		0.8		(V _{out} - V _{ref}) @ I _{pn}
Internal output resistance	R _{out}	Ω		1		Output
Quiescent voltage	V _{off}	V	2.48	2.5	2.52	V _{out} @ 0 A
Electrical offset voltage	V _{oe}	mV	-10		10	(V _{out} - V _{ref}) @ 0 A
Temperature drift of V _{oe}	V _{oe} _TRange	%V _{FS}	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I _{om}	A	-0.25		0.25	@ ±10 x I _{pn}
Theoretical gain	G _{th}	mV/A		8		800 mV @ I _{pn}
Error of gain	Err _G	%G _{th}		±1		Trimmed in the factory @ 25°C
Temperature drift of gain	G _{TR}	%G _{th}	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L _{pn}	%I _{pn}	-0.5		0.5	±I _{pn}
Linearity error @ I _{pm}	Non-L _{pm}	%I _{pm}	-3		3	±I _{pm}
Reaction time	t _{ra}	μs		0.4		@ 10% of I _{pn}
Step response time	t _{res}	μs		1.5		@ 90% of I _{pn}
Delay time	t _{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V _{noise}	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I _{pn}	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I _{pn}	-2		2	-40°C ~ 105°C

8. STK-120PL/Z Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I _{pn}	A		120		
Primary current measuring range	I _{pm}	A	-300		300	
Supply voltage	V _{cc}	V	4.75	5	5.25	
Current consumption	I _{cc}	mA		5	10	
Reference voltage	V _{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V _{FS}	V		0.8		(V _{out} - V _{ref}) @ I _{pn}
Internal output resistance	R _{out}	Ω		1		Output
Quiescent voltage	V _{off}	V	2.48	2.5	2.52	V _{out} @ 0 A
Electrical offset voltage	V _{oe}	mV	-10		10	(V _{out} - V _{ref}) @ 0 A
Temperature drift of V _{oe}	V _{oe} _TRange	%V _{FS}	-1.5		1.5	-40°C ~ 105°C
Magnetic offset current	I _{om}	A	-0.25		0.25	@ ±10 x I _{pn}
Theoretical gain	G _{th}	mV/A		6.667		800 mV @ I _{pn}
Error of gain	Err _G	%G _{th}		±1		Trimmed in the factory @ 25°C
Temperature drift of gain	G _{TR}	%G _{th}	-1.0		1.0	-40°C ~ 105°C
Rated linearity error	Non-L _{pn}	%I _{pn}	-0.5		0.5	±I _{pn}
Linearity error @ I _{pm}	Non-L _{pm}	%I _{pm}	-3		3	±I _{pm}
Reaction time	t _{ra}	μs		0.4		@ 10% of I _{pn}
Step response time	t _{res}	μs		1.5		@ 90% of I _{pn}
Delay time	t _{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V _{noise}	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I _{pn}	-1		1	@ 25°C
Accuracy @ -40°C ~ 105°C	X_TRange	% of I _{pn}	-2		2	-40°C ~ 105°C

9. STK-150PL/Z Electrical performance

Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 5\text{ V}$ (Except special instructions)

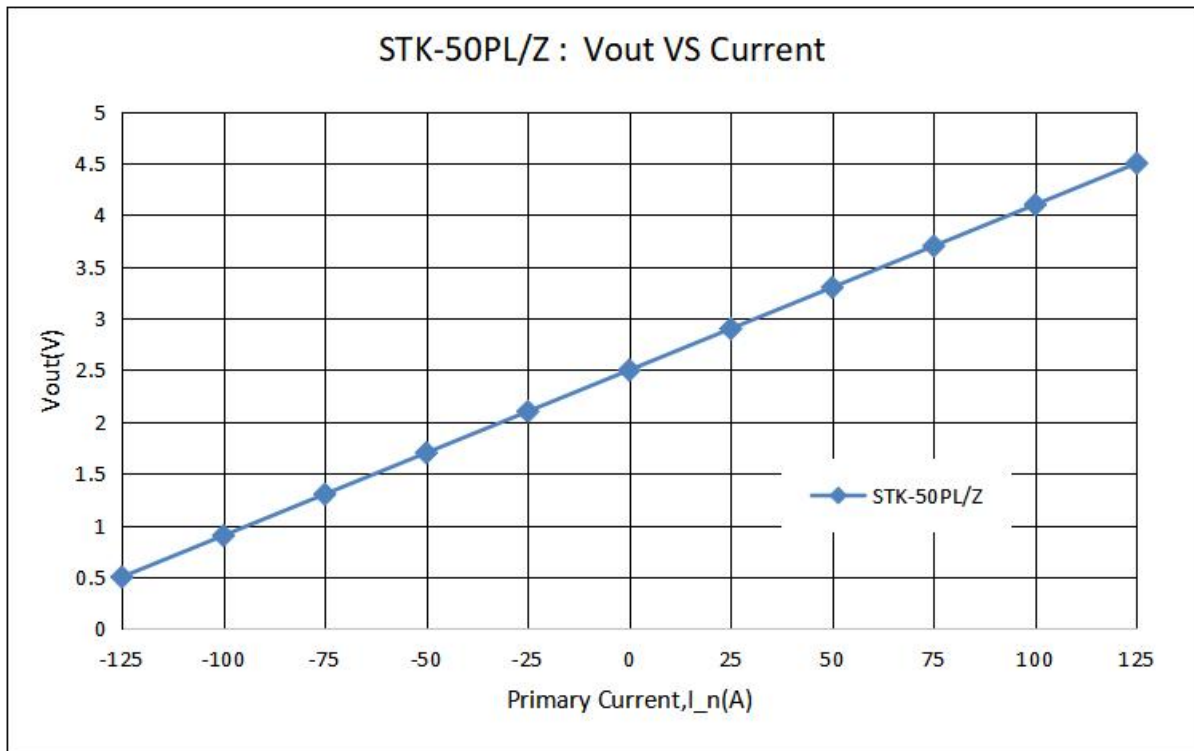
Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		150		
Primary current measuring range	I_{pm}	A	-375		375	
Supply voltage	V_{cc}	V	4.75	5	5.25	
Current consumption	I_{cc}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		5.33		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Rated linearity error	$Non-L_{pn}$	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	$Non-L_{pm}$	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.4		@ 10% of I_{pn}
Step response time	t_{res}	μs		1.5		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz				15		
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^\circ\text{C} \sim 105^\circ\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^\circ\text{C} \sim 105^\circ\text{C}$

10. STK-180PL/Z Electrical performance

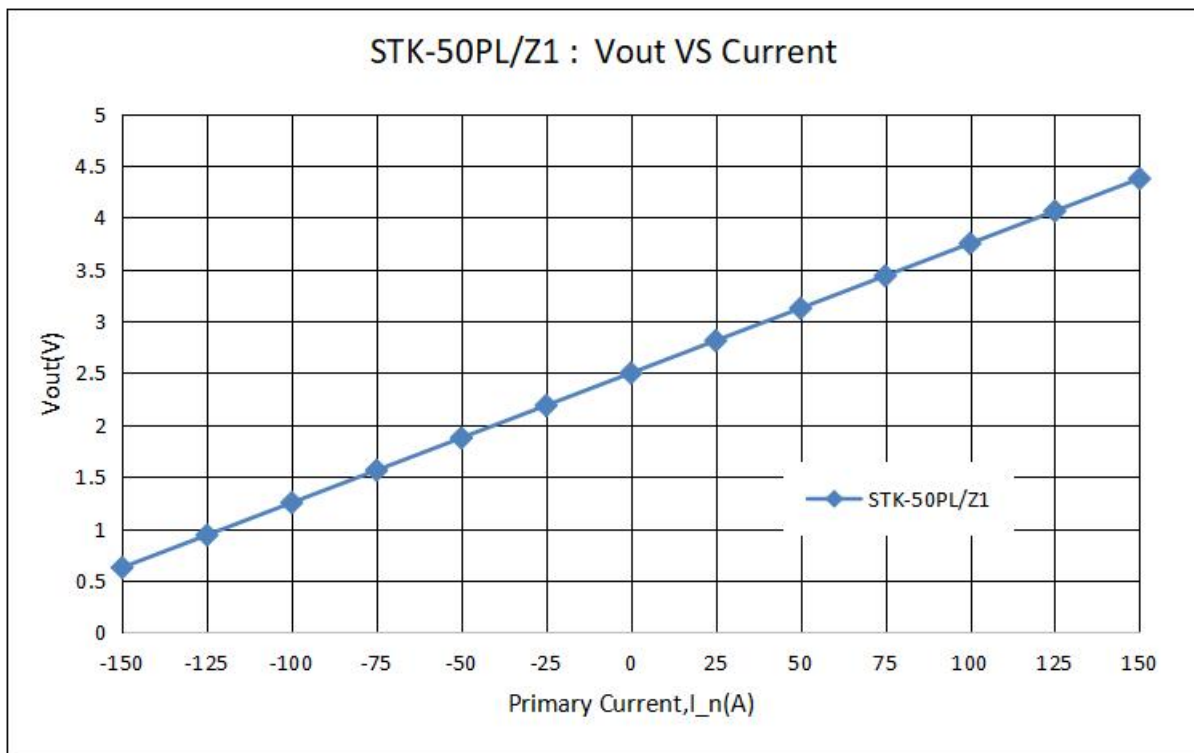
Condition: $T_A = 25^\circ\text{C}$ $V_{cc} = 5\text{V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		180		
Primary current measuring range	I_{pm}	A	-375		375	
Supply voltage	V_{cc}	V	4.75	5	5.25	
Current consumption	I_{cc}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		4.44		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^\circ\text{C} \sim 105^\circ\text{C}$
Rated linearity error	$Non-L_{pn}$	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	$Non-L_{pm}$	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.4		@ 10% of I_{pn}
Step response time	t_{res}	μs		1.5		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		400 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		400		No RC circuit
Output voltage noise	V_{noise}	mVpp				
DC ~ 10 kHz			10			
DC ~ 100 kHz	15					
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^\circ\text{C} \sim 105^\circ\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^\circ\text{C} \sim 105^\circ\text{C}$

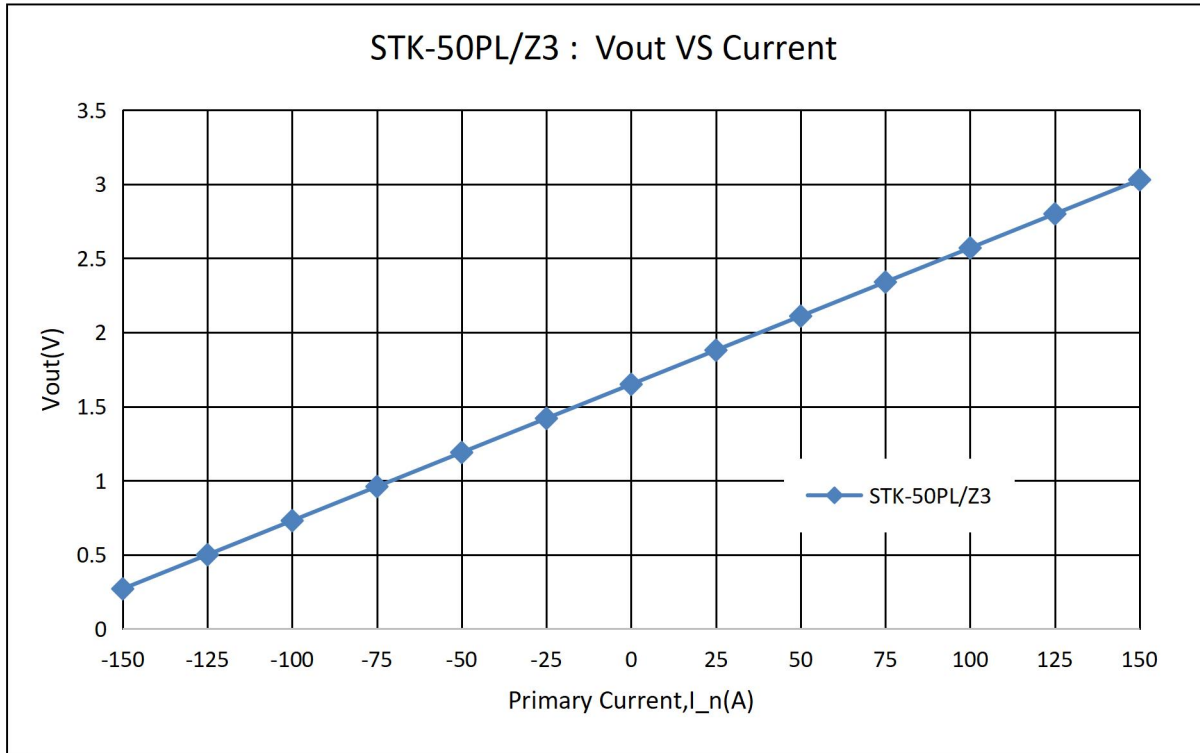
11. Output voltage VS primary current



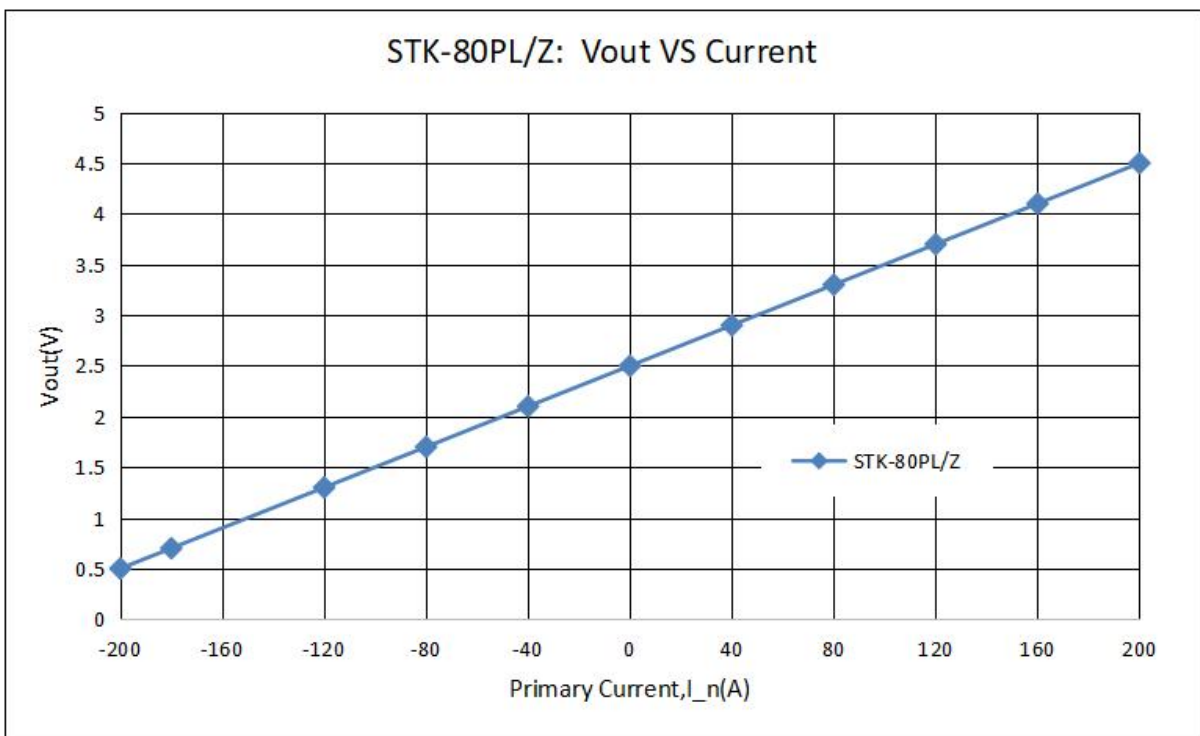
The dependence of Vout of STK-50PL/Z on the primary current.



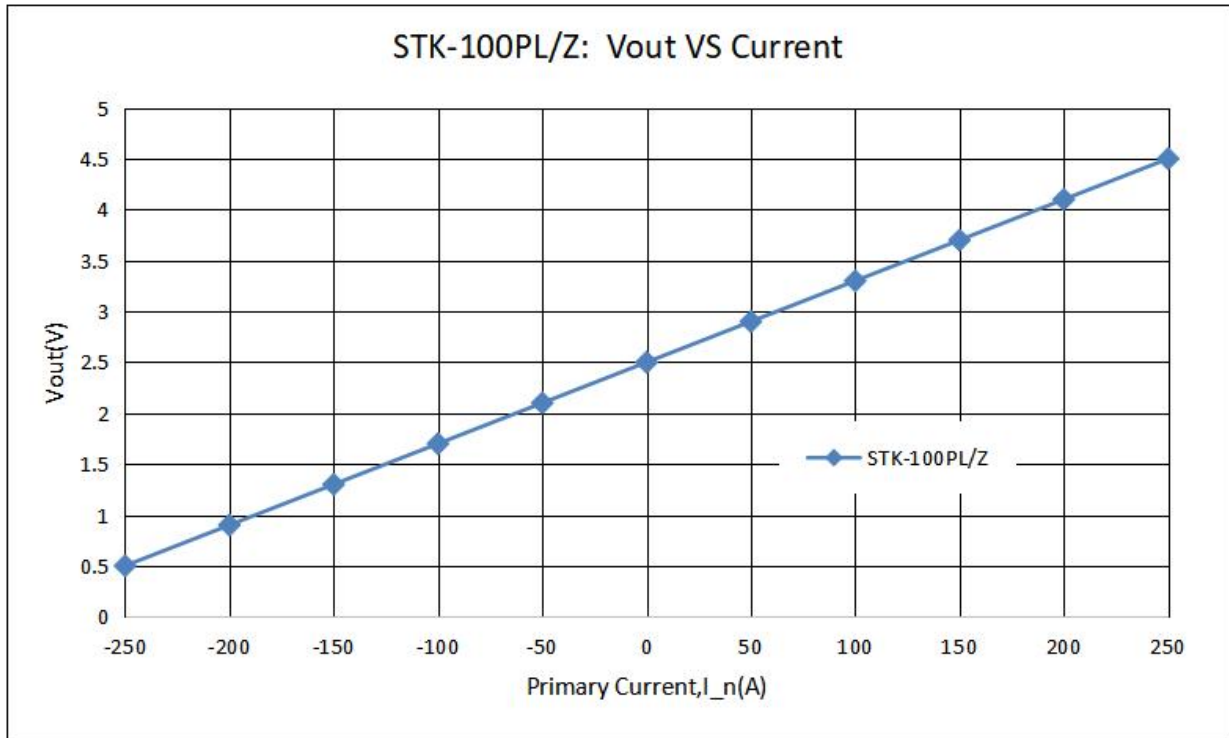
The dependence of Vout of STK-50PL/Z1 on the primary current.



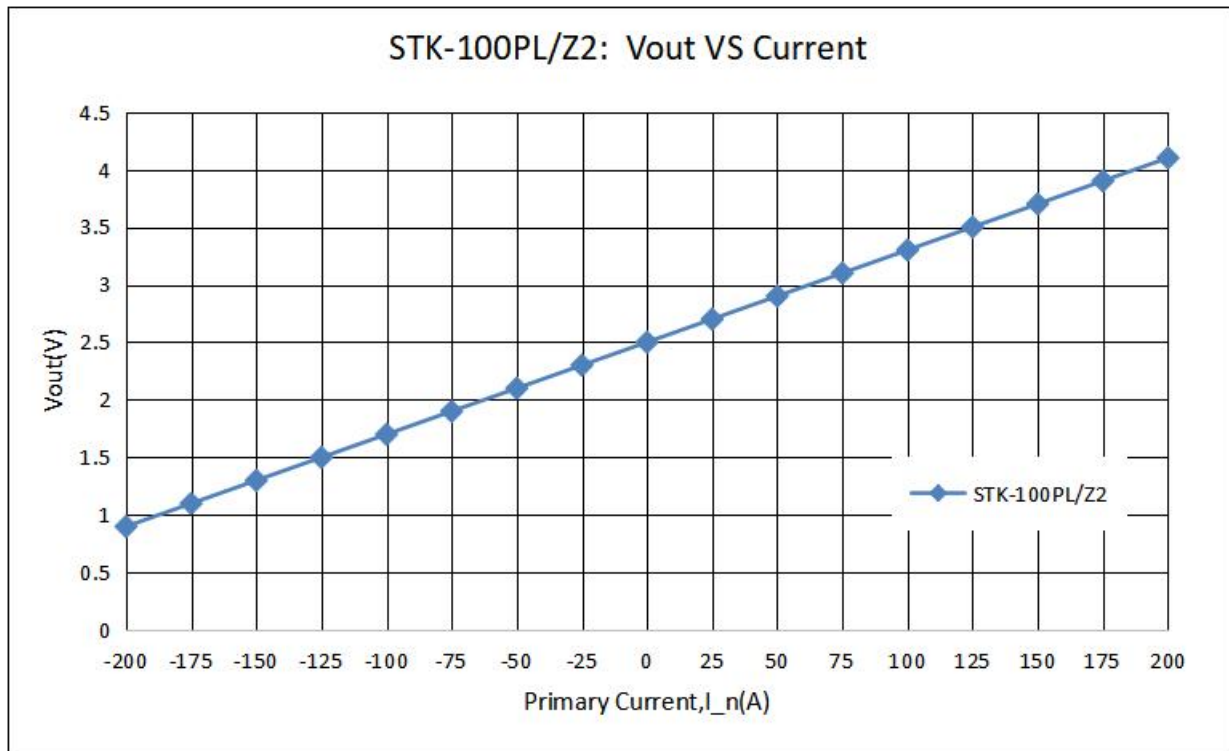
The dependence of Vout of STK-50PL/Z3 on the primary current.



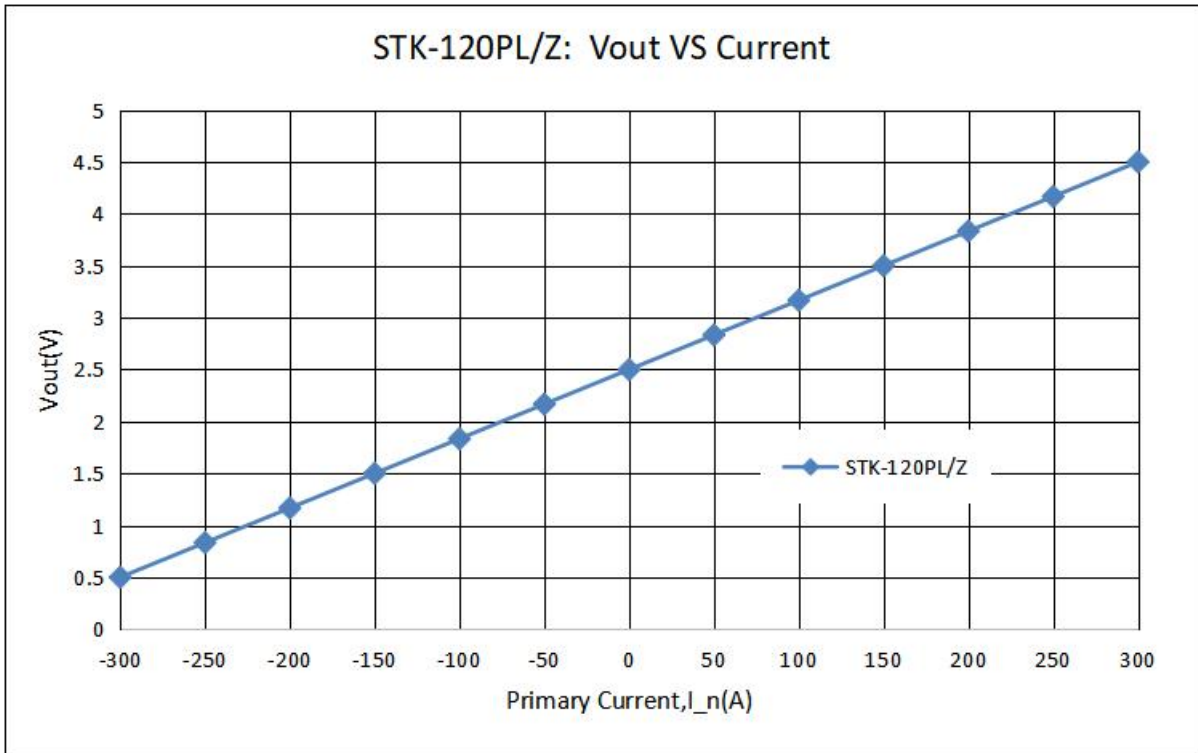
The dependence of Vout of STK-80PL/Z on the primary current.



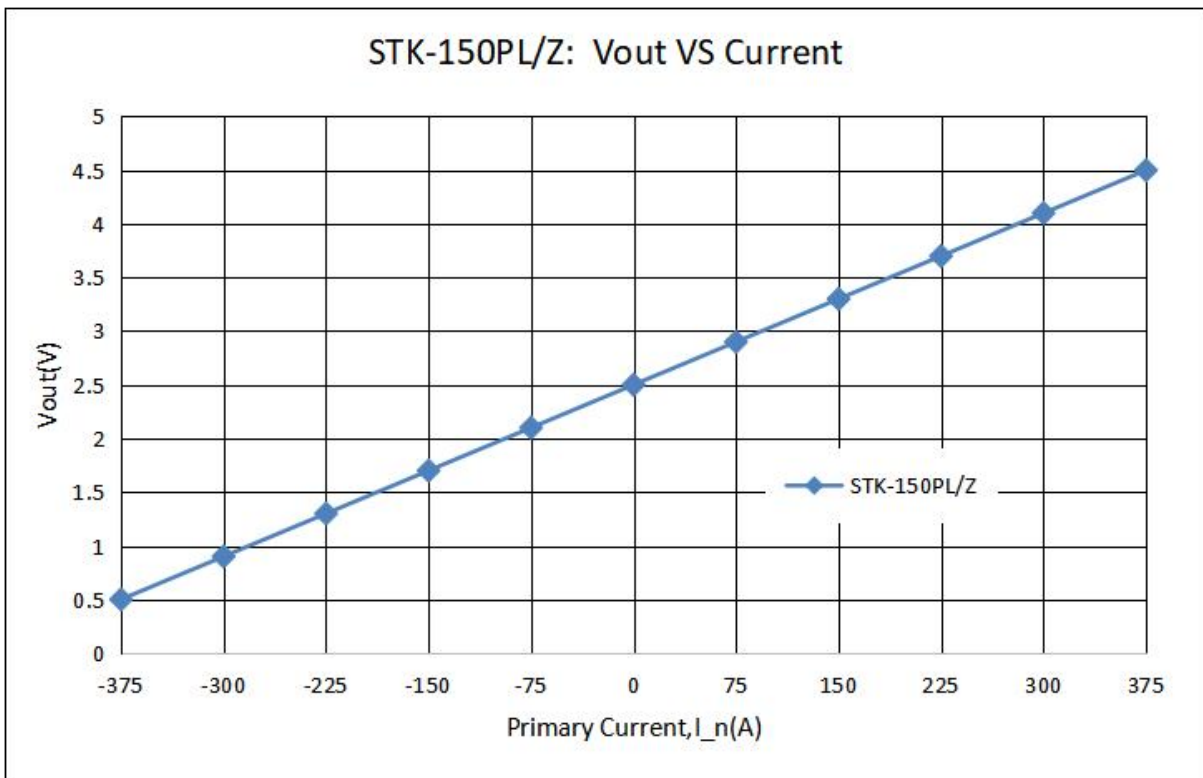
The dependence of Vout of STK-100PL/Z on the primary current.



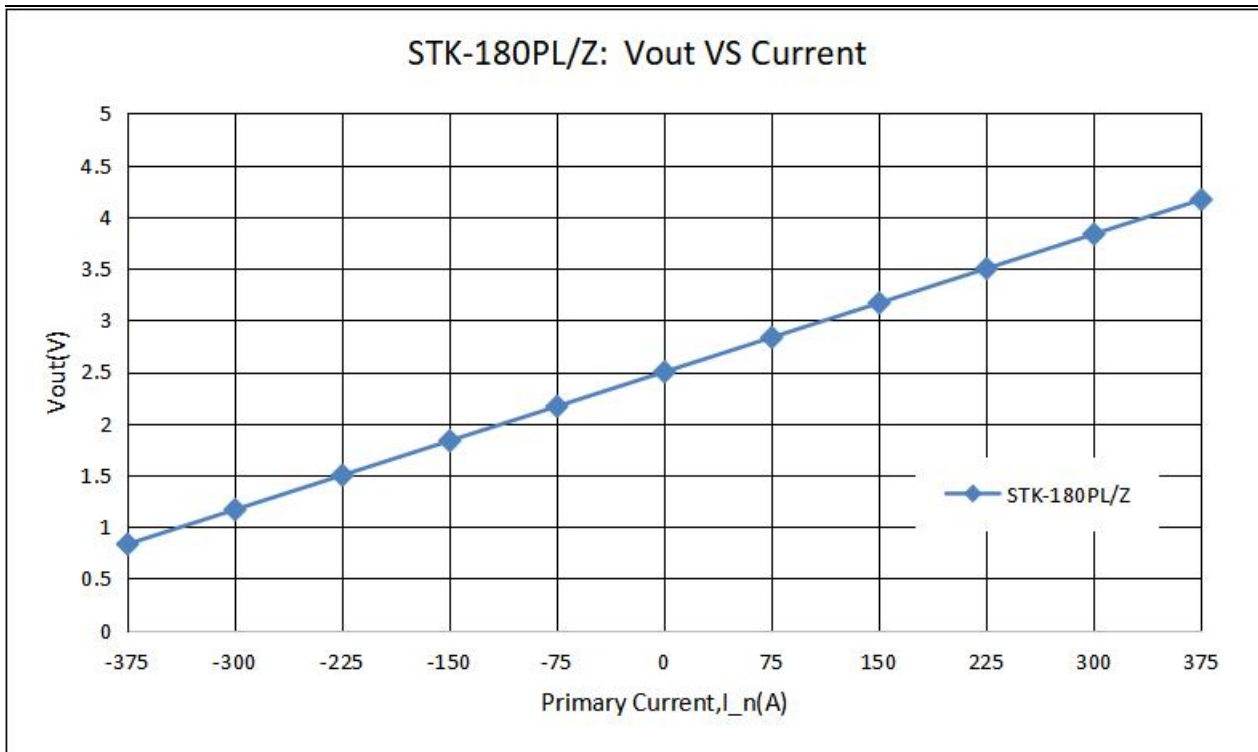
The dependence of Vout of STK-100PL/Z2 on the primary current.



The dependence of Vout of STK-120PL/Z on the primary current.

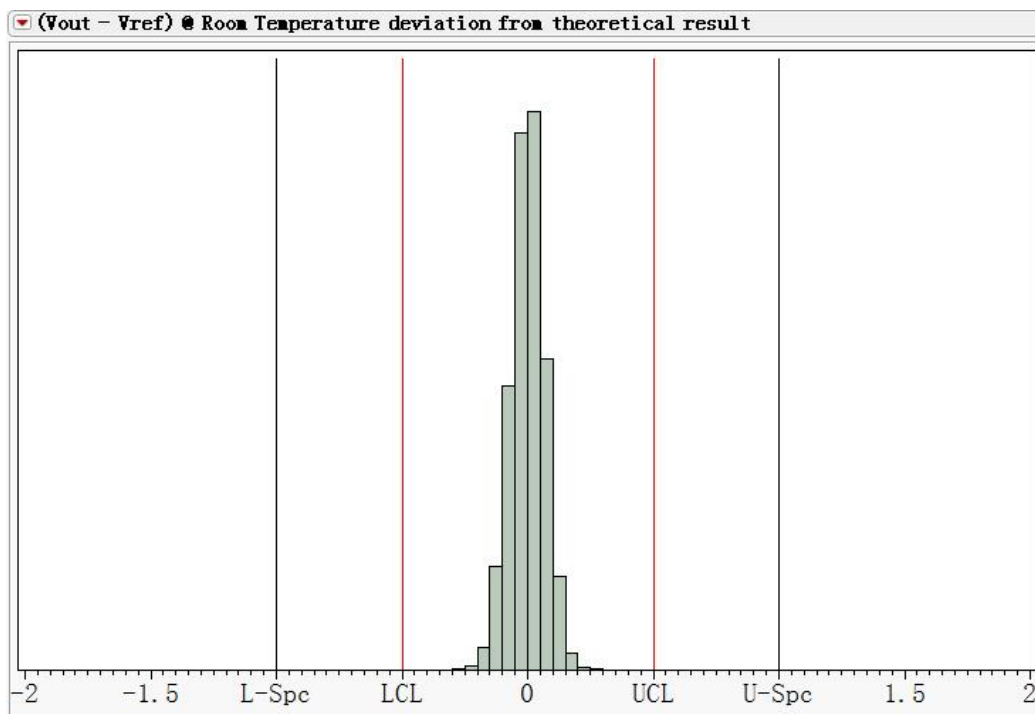


The dependence of Vout of STK-150PL/Z on the primary current.



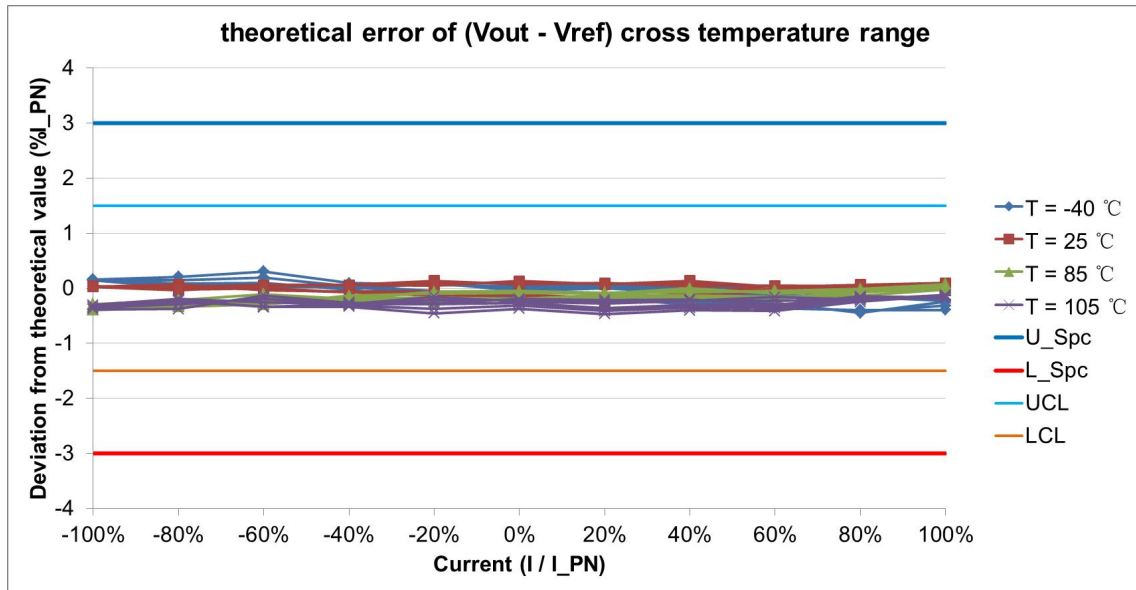
The dependence of Vout of STK-180PL/Z on the primary current.

12. Accuracy characteristics in room temperature

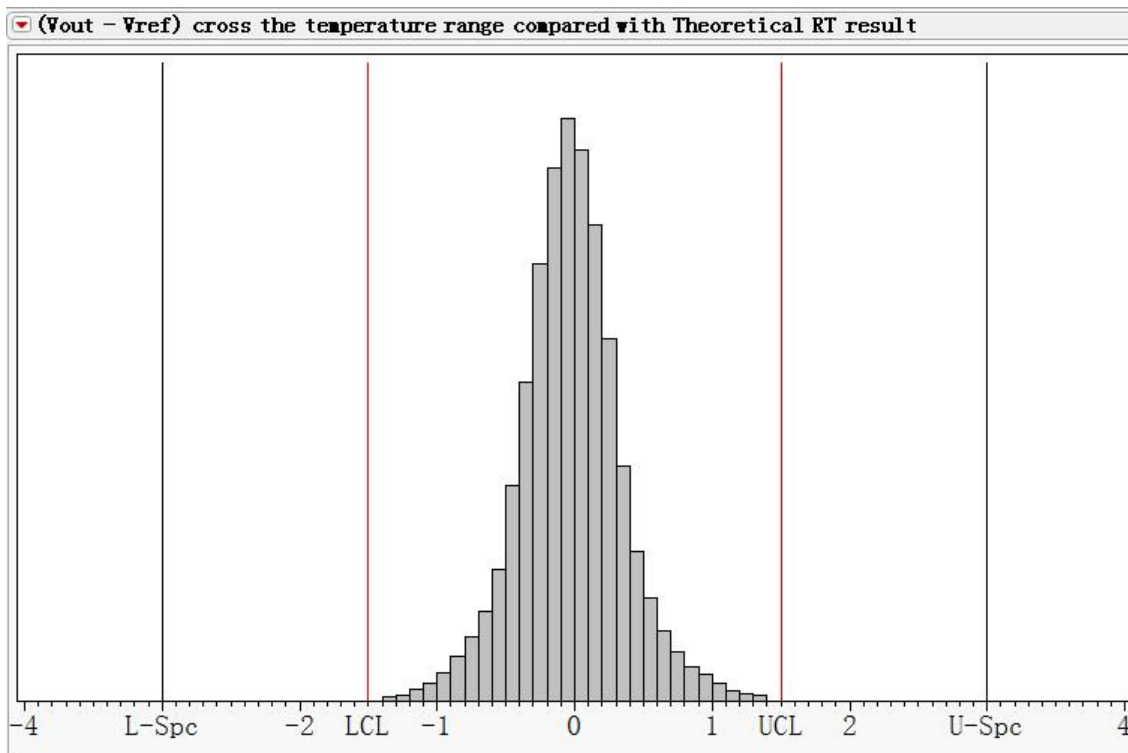


The error of STK-PL/Z current sensor at 25 °C compared with the standard output , $((V_{out} - V_{ref})_{measure} @ I_n @ 25^{\circ}C - V_{oe}@25^{\circ}C - G_{th} * I_n) / V_{FS}$. Vout represents voltage of Vout, Vref the voltage of Vref, I_n the primary current, V_{oe} the (Vout - Vref)_{@0A}, G_{th} the theoretical gain, V_{FS} the rated output voltage.

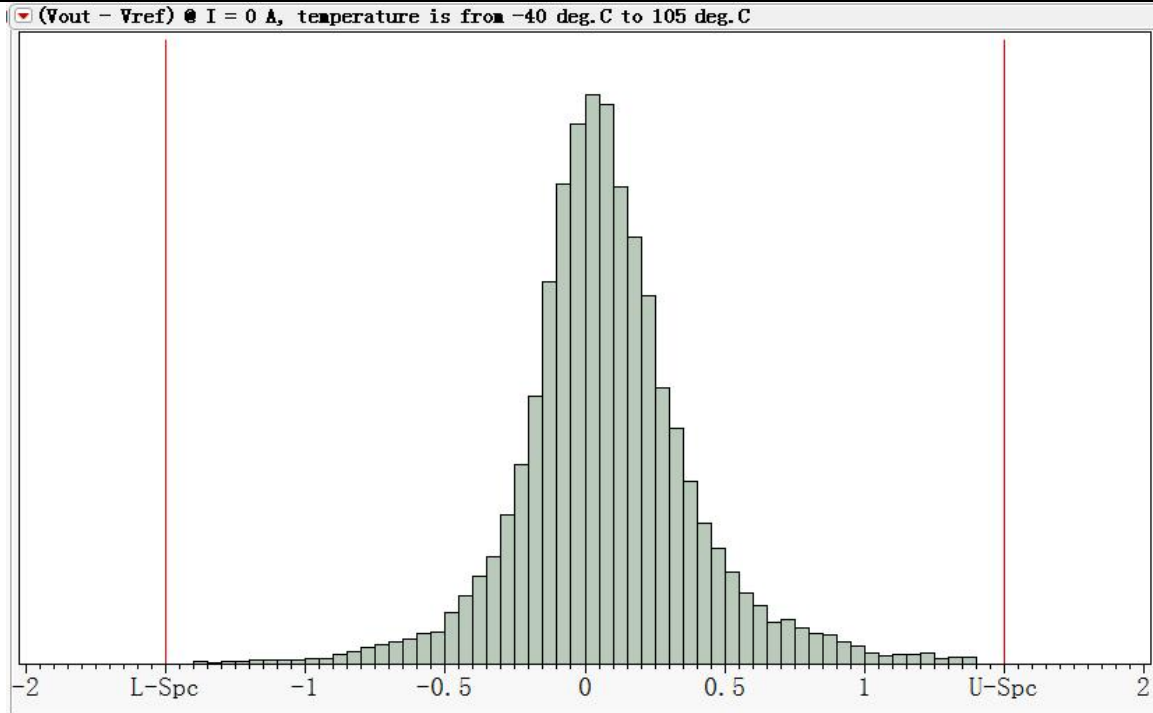
13. Accuracy cross temperature



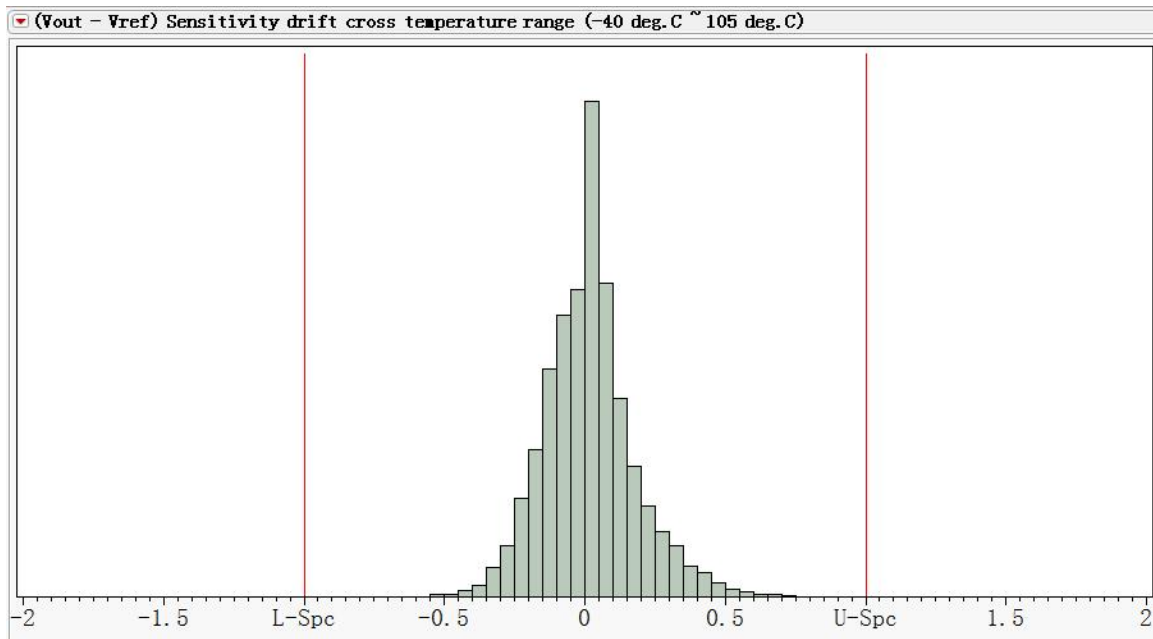
The error of STK-PL/Z current sensor at $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$ compared with the standard output at room temperature, $((V_{out} - V_{ref})_{measure} @ I_n @ T_x - V_{oe} @ T_x - G_{th} * I_n) / V_{FS}$. Where, V_{out} represents voltage of V_{out} , V_{ref} the voltage of V_{ref} , I_n the primary current, T_x the present temperature, V_{oe} the $(V_{out} - V_{ref}) @ 0A$, G_{th} the theoretical gain, V_{FS} the rated output voltage.



The error of STK-PL/Z output $(V_{out} - V_{ref})$ current sensor at $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$ compared with the standard output $(V = G_{th} * I_n)$, $((V_{out} - V_{ref}) @ I_n @ T_x - G_{th} * I_n) / V_{FS}$, Where, I_n represents present primary current, T_x the present temperature, G_{th} the theoretical gain, V_{FS} the rated output voltage.

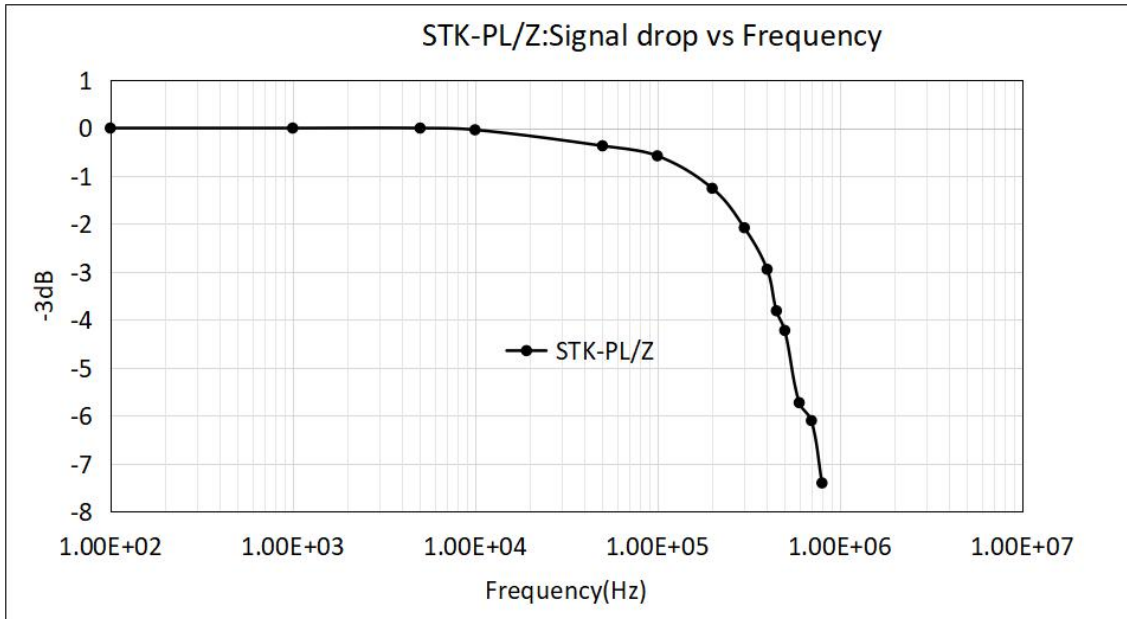


Temperature drift of Voe, $V_{oe_TRange} = (V_{oe} @ T_x - V_{oe} @ 25^{\circ}C) / V_{FS}$. T_x represents present temperature, V_{FS} the rated output voltage.



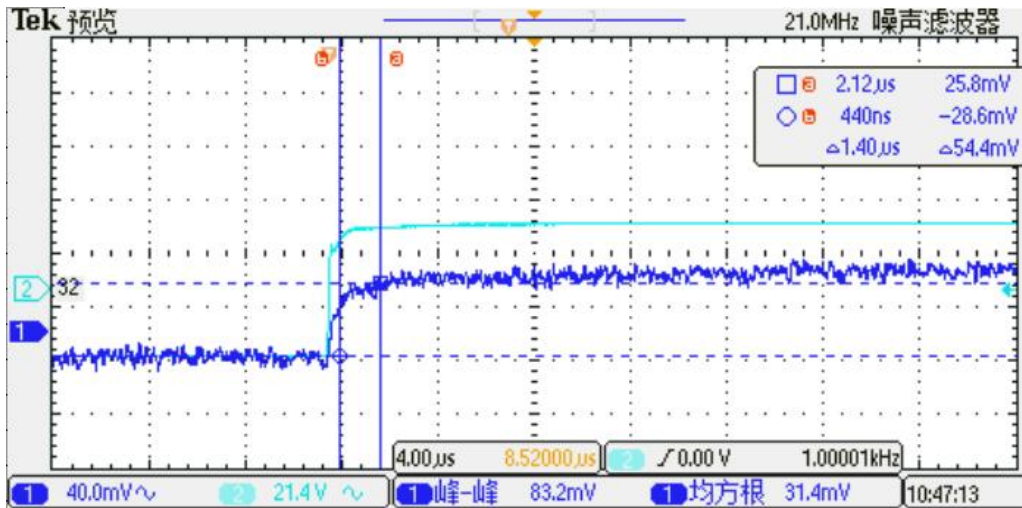
Error of gain, $Err_G = (((V_{out} - V_{ref}) @ I_{pn} - (V_{out} - V_{ref}) @ (-I_{pn})) / 2) - V_{FS} / V_{FS}$. Where I_{pn} represents the rated current, $-I_{pn}$ the reversed rated current.

14. Frequency response and bandwidth



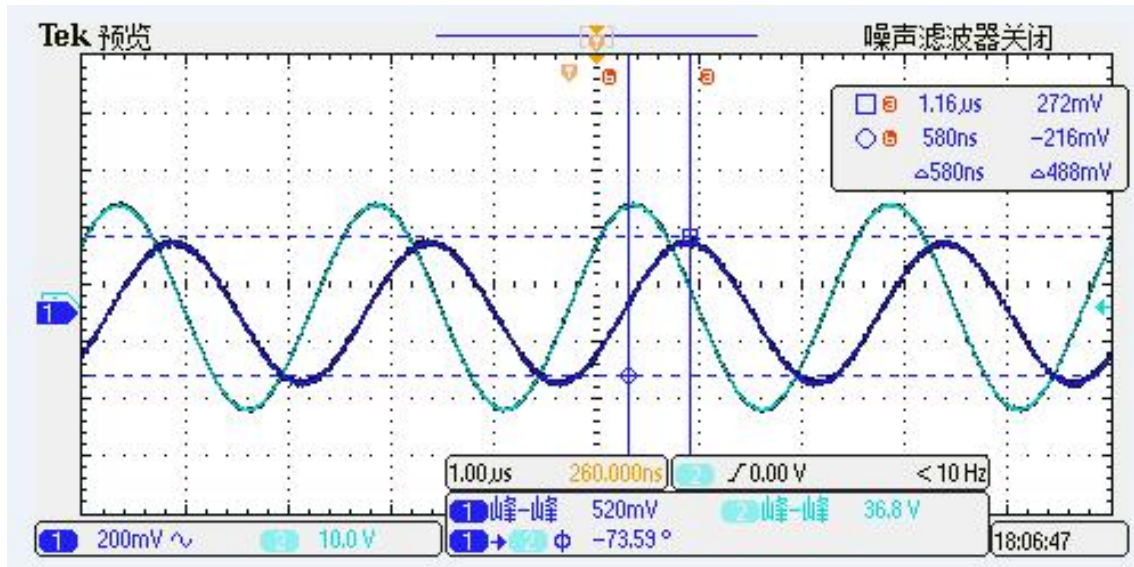
The frequency bandwidth of STK-xxPL/Z series current sensor. The bandwidth of current sensor is DC ~ 400 kHz (-3dB).

15. Step response time



The typical frequency response of STK-xxPL/Z current sensor. The response time from 90% of the primary current (light blue) to 90% of the secondary output (dark blue) is less than 1.5 µs

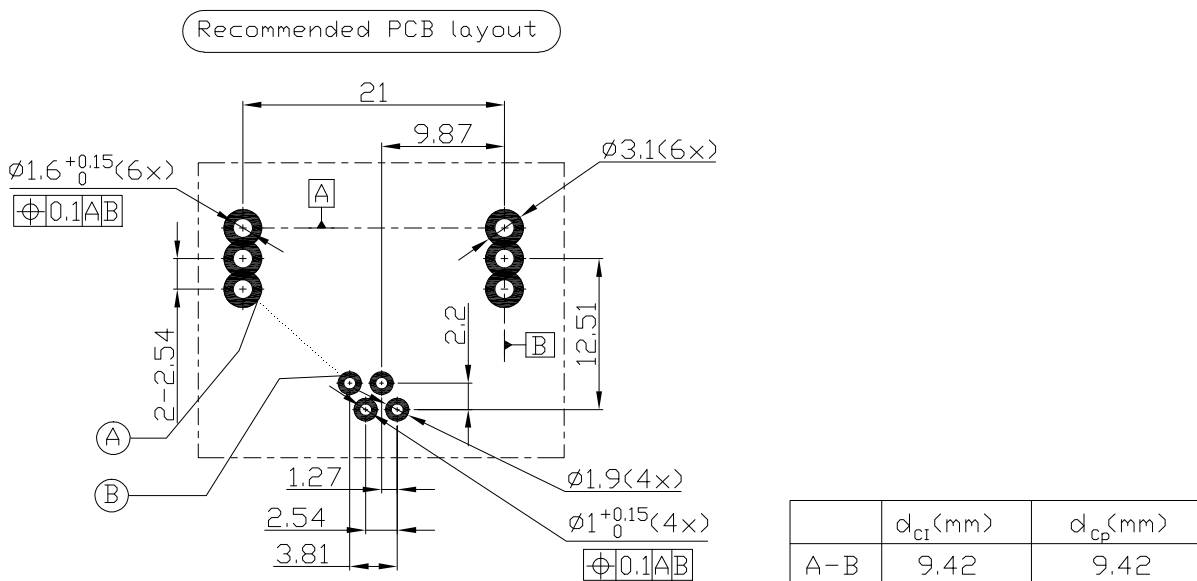
16. Frequency delay performance



When testing 400 kHz sine wave, the typical result of STK-xxPL/Z current sensor's output. The response time from the primary current (light blue) to the secondary output (dark blue) is less than 0.8μ s.

17. Recommended PCB layout

Installation of view: overlooking (unit: mm)



1. Installing angle: Overlook (observe from the side of installing transducer)
2. Recommended bore diameter of primary current line, (diameter of primary current $\times 1.2$) mm
3. Recommended bore diameter of secondary current line, (diameter of secondary current $\times 1.2$) mm
4. The maximum thickness of PCB is 2.5 mm
5. The curve of wave soldering: $260^{\circ}\text{C} \times 10 \text{ s}$

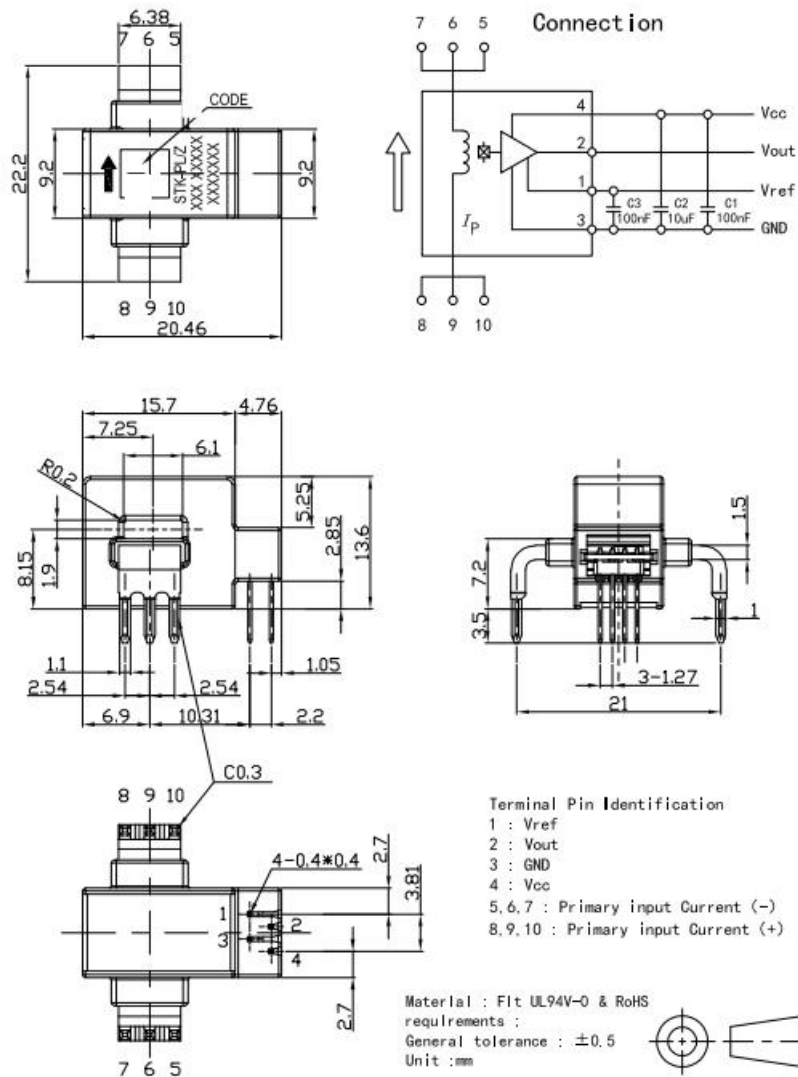


Security:

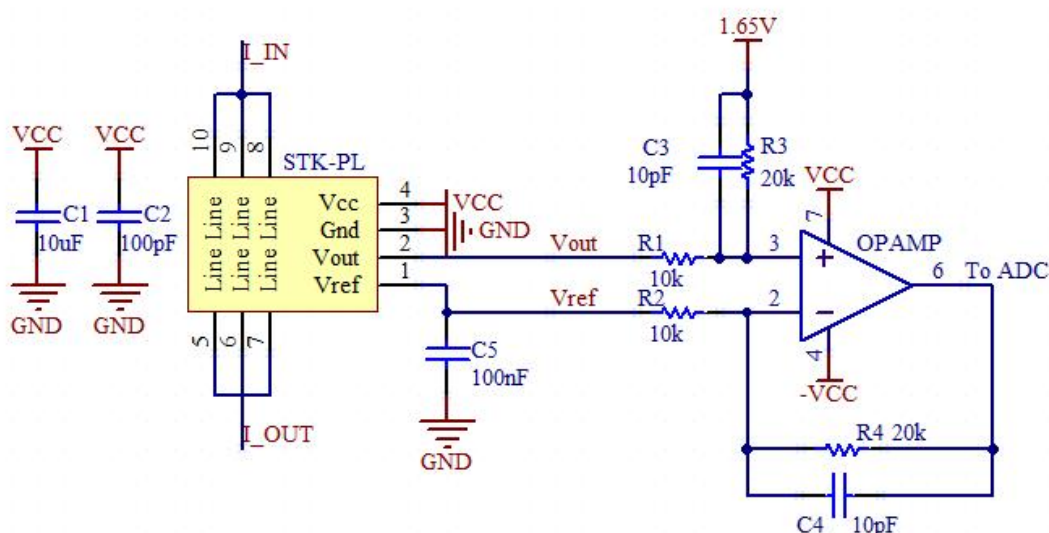
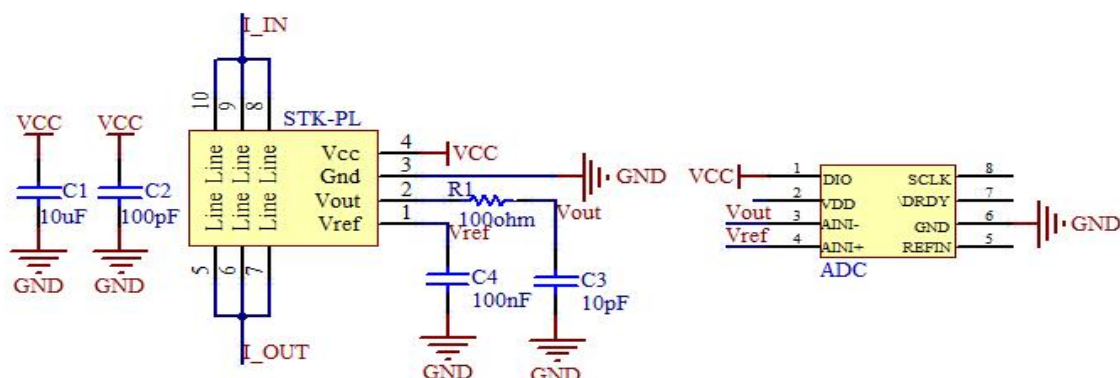
This current sensor must be used in limited-energy secondary circuit according to IEC 61010-1.

- This current sensor must be used in electric/electronic equipment with respect to appliance standards and safety requirement in accordance with the manufacture's operating instructions;
- When operating the current sensor, certain parts of the module can carry hazardous voltage;
- Failure to wiring as shown in the diagram will damage the current sensor;
- Ignoring this warning can lead to serious consequences.
- A protective housing or a additional shield could be used.
- Main supply must be able to disconnected.

18. Dimension & Pin definitions



19. Appendix: typical application circuit



R3 (kohm)	C3 (pF)	Theoretical -3dB $f = 1/(2\pi RC)$ (kHz)	Measured -3dB (kHz)
20	20	398	~400
20	81	98	~ 100
20	810	10	~ 10

The frequency characteristics of STK-xxPL/Z series current sensor are not affected by the R-C setting (according to recommended R-C setting), therefore the active filter circuit or R-C circuit can be applied to modulate the sensor's frequency characteristics.

The signal input to ADC is $1.65 + R4/R2 * (Vout - Vref)$ with the conditions: $R1 = R2, R3 = R4, C3 = C4$.